

/ Descriptions

WR0459I ММ Ё SQS æ Ñ ç s ll 1 Silicon PNP transistor in a TO-126F Plastic Package.

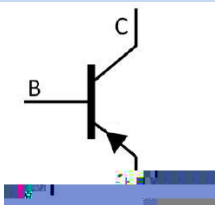
/ Features

лъ 5VG99<+D, Ы ´
Complementary pair with 2SD669(A).

/ Applications

æ ã ã H l i ' ð z
Low frequency power amplifier.

/ Equivalent Circuit



/ Pinning

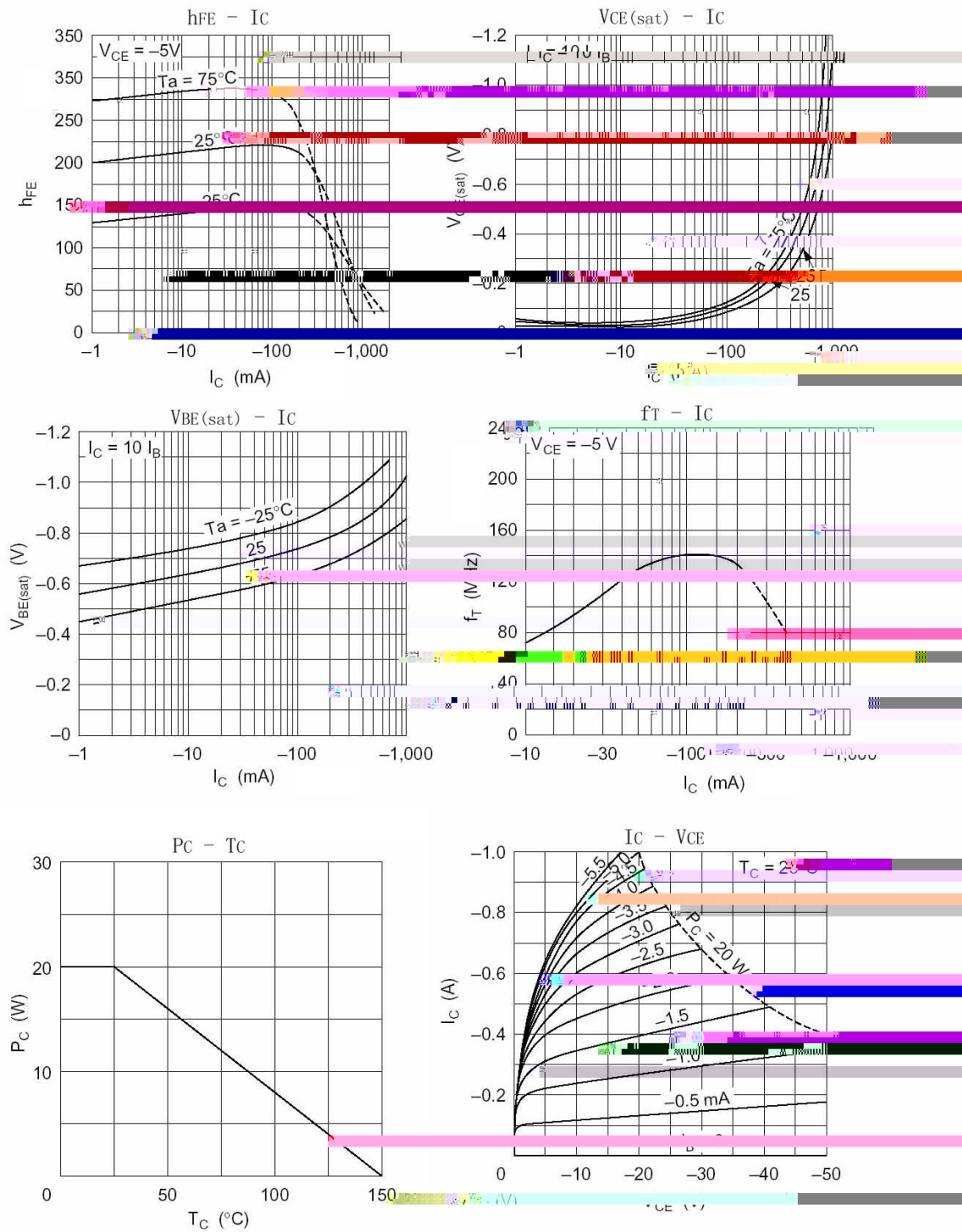


PIN1 χ Emitter PIN 2 χ Collector PIN 3 χ Base

/ h_{FE} Classifications & Marking

h _{FE} Classifications Symbol	B	C	D
h _{FE} Range	60 120	100 200	160 320

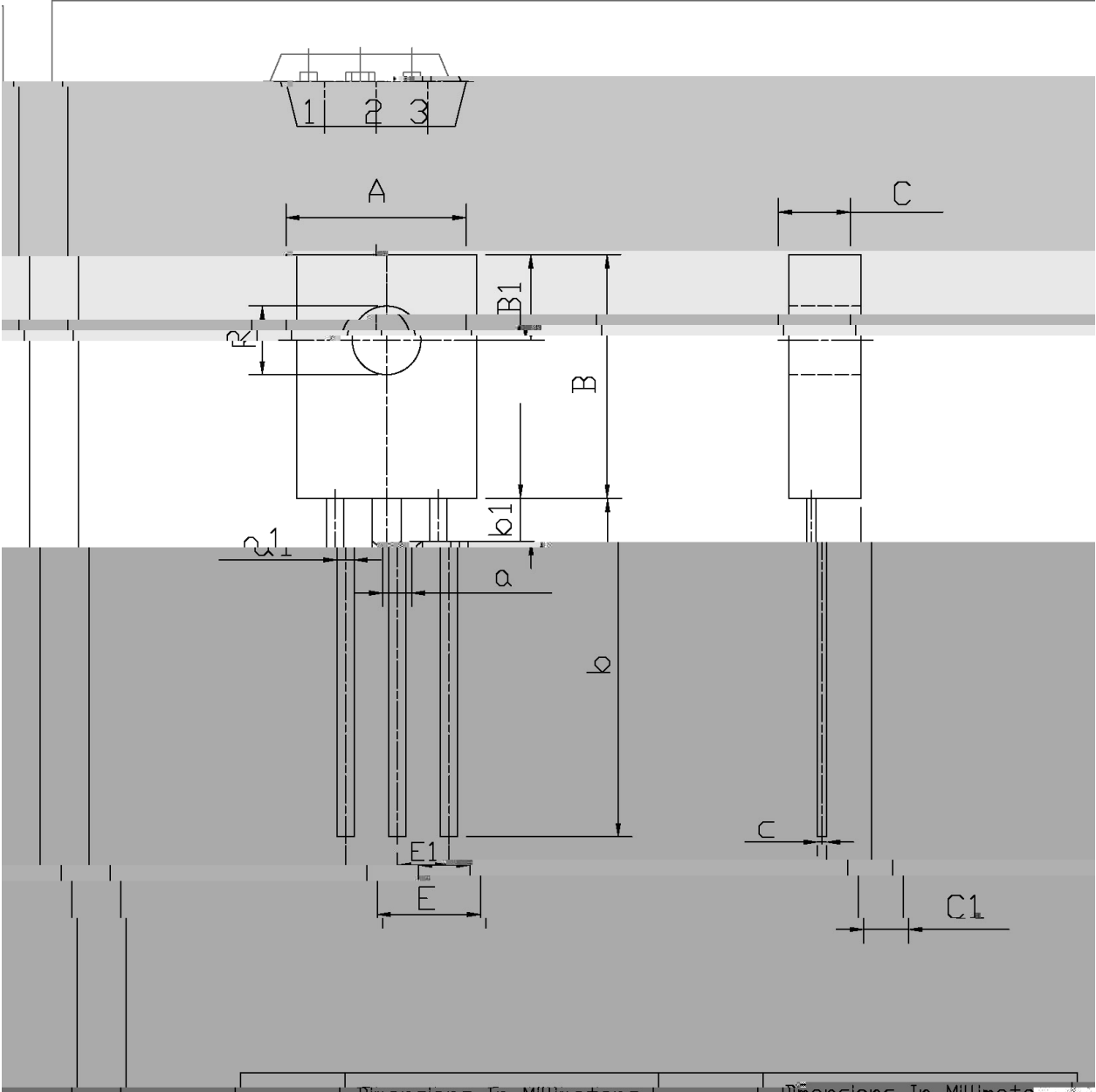
/ Electrical Characteristic Curve



/ Package Dimensions

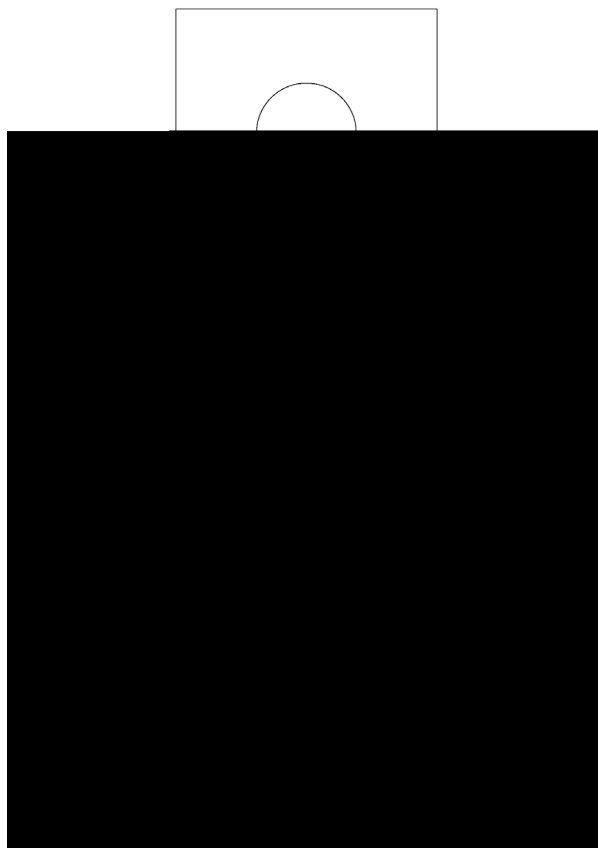
1U-126F

单位: mm



Symbol	Min	Max	Symbol	Min	Max
A	7.8	8.2	a1	0.65	
B	10.8	11.2	E	0.4	

/ Marking Instructions



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EU χ

$$E_{97} < \chi$$
$$E =$$

---X

Note:

BR:

B649 :

B:

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$$k_{IH} \approx 6 \text{ } \mu\text{g}$$
$$\mathbb{H} \cdot f \check{\eta}^N \Gamma_D \quad \text{I} \otimes \cdot f \check{\eta}^N \Psi \mathcal{P}$$

Company Code

Product Type.

h_{FE} Classifications Symbol

Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



б " X

- 1. 150~255 °C, Time: 60~90sec;
- 2. 255 °C, Duration: 5~0.5sec;
- 3. Cooling Speed: 2~10 °C/sec.

- Note:
- 1.Preheating:25~150 °C , Time:60~90sec.
 - 2.Peak Temp.:255 °C , Duration:5~0.5sec.
 - 3. Cooling Speed: 2~10 °C/sec.

5 • 2 5 255 °